

New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.
SPRINGFIELD, NEW JERSEY 07081
U.S.A.

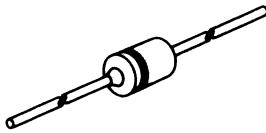
TELEPHONE: (973) 376-2922
(212) 227-6005
FAX: (973) 376-8960

RECTIFIERS

High Efficiency, ESP, 2.5 Amp to 20 Amp

FEATURES

- Exceptional Efficiency
- Low Forward Voltage
- Extremely Fast Reverse Recovery Time
- Extremely Fast Forward Recovery Time
- High Surge
- Small Size
- Rugged, High Current Termination



1N5802-1N5806
1N5807-1N5811
1N5812-1N5816

DESCRIPTION

This series of High Efficiency Power Rectifiers allows circuit designers to design high current, high frequency supplies to 500 kHz with very low diode losses. The high forward surge capability makes these devices useful in protective circuits.

ABSOLUTE MAXIMUM RATINGS

Peak Inverse Voltage	2.5 Amp Series	5 Amp Series	20 Amp Series
50V	1N5802	1N5807	1N5812
75V	1N5803	1N5808	1N5813
100V	1N5804	1N5809	1N5814
125V	1N5805	1N5810	1N5815
150V	1N5806	1N5811	1N5816

Maximum Average D.C. Output Current

② $T_L = 75^\circ\text{C}$, $L = \frac{3}{4}\text{''}$ 2.5A 6.0A 20.0A
② $T_C = 100^\circ\text{C}$ — — —

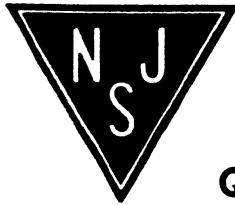
Non-Repetitive Sinusoidal

Surge Current (8.3ms) 35A 125A 250A
Operating and Storage Temperature Range -65°C to $+175^\circ\text{C}$
Thermal Resistance 2.5A and 5A Series See Lead Temperature Derating Curve
20A Series 3.0°C/W

ELECTRICAL SPECIFICATIONS (at 25°C unless noted)

Type	PIV	Maximum Forward Voltage Drop*	Leakage Current @ PIV		Maximum Reverse Recovery Time I_F , I_R , μsec	Typical Forward Recovery Time @ 1A Recover to 1V	Typical Forward Recovery Voltage @ 1A tr = 5ms	Typical Junction Capacitance @ -10V
			25°C	100°C				
1N5802	50V							
1N5803	75V							
1N5804	100V	1.0 @ 1A	1 μA	50 μA	25ns, 0.5A-0.5A-0.05A	25ns	1.5V	15pf
1N5805	125V							
1N5806	150V							
1N5807	50V							
1N5808	75V							
1N5809	100V	1.0 @ 4A	5 μA	150 μA	30ns, 1.0-1.0-0.1A	25ns	1.5V	45pf
1N5810	125V							
1N5811	150V							
1N5812	50V							
1N5813	75V							
1N5814	100V	1.0 @ 10A	10 μA	750 μA	35ns; 1.0-1.0-0.1A	25ns	1.5V	200pf
1N5815	125V							
1N5816	150V							

*Pulse width = 250ms



Quality Semi-Conductors

PACKAGE OUTLINE

